Vishay Semiconductors

Hyperfast Rectifier, 15 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)} 15 A						
V _R	600 V					
V _F at I _F at 125 °C	1.3 V					
t _{rr} (typ.)	19 ns					
T _J max.	175 °C					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

- Best in class forward voltage drop and switching losses trade off
- · Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- Polyimide passivation
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 129 °C, D = 0.50	15					
Repetitive peak forward current	I _{FRM}	T _C = 129 °C, D = 0.50, f = 20 kHz	30	А				
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	185]				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX.						
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
Forward voltage	VF	I _F = 15 A	-	1.6	2.1	V		
Forward voltage	۷F	I _F = 15 A, T _J = 125 °C	-	1.3	-			
Deverse leakerse eurrent	1	$V_{R} = V_{R}$ rated	-	-	10			
Reverse leakage current	IR	I_R T _J = 125 °C, V _R = V _R rated -			500	μA		
Junction capacitance	CT	V _R = 200 V -		25	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS			
		I _F = 1.0 A,dI _F /dt = 100 A/µs, V _R = 30 V		-	19	-	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	23	-	ns		
		T _J = 125 °C		-	36	-			
Peak recovery current	1	T _J = 25 °C	$I_{\rm F} = 10 {\rm A}$	-	12	-	А		
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs V _R = 400 V	-	20	-	~		
Reverse recovery charge	0	T _J = 25 °C		-	180	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	472	-	ΠC		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	33	-	ns		
neverse recovery time	۲r	T _J = 125 °C		-	44	-			
Pook receivery ourrent	I _{RRM}	T _J = 25 °C	I _F = 15 A dI _F /dt = 1000 A/μs V _B = 400 V	-	13	-	A		
Peak recovery current		T _J = 125 °C		-	21	-			
	0	T _J = 25 °C		-	220	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	578	-	ПС		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.72	°C/W		
Weight			-	2.0	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-220AC 2L	E5TX1506					

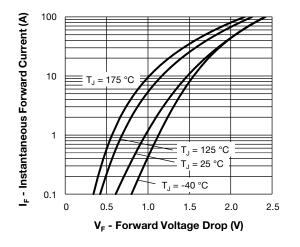


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

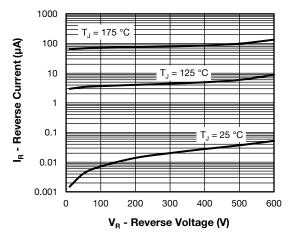


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg



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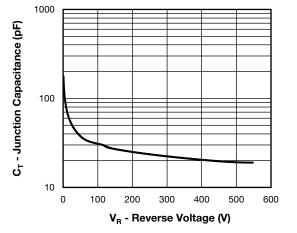


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

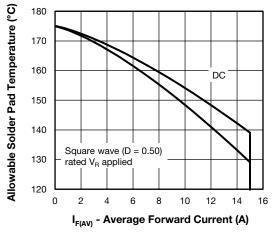


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

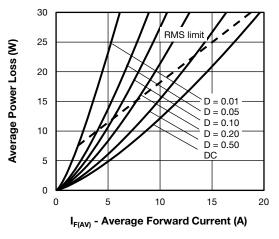


Fig. 5 - Forward Power Loss Characteristics, Per Leg

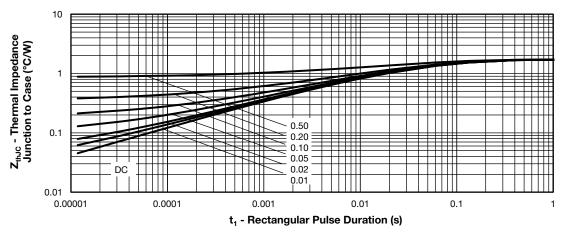


Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

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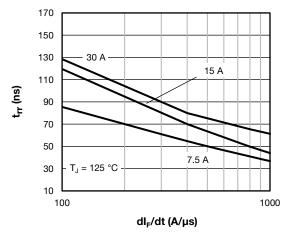


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

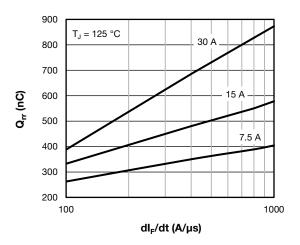


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

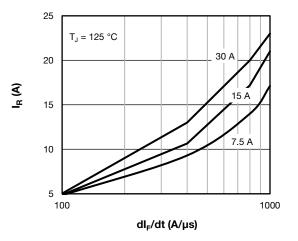


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

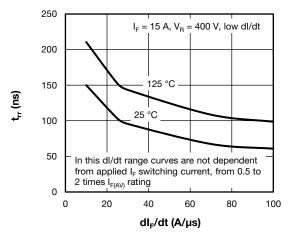


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

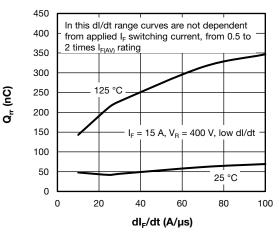


Fig. 11 - Typical Reverse Recovery Charge vs. $dI_{\ensuremath{\text{F}}\xspace}/dt,$ Per Leg

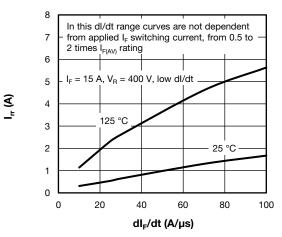


Fig. 12 - Typical Reverse Recovery Current vs. dI_F/dt , Per Leg

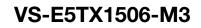
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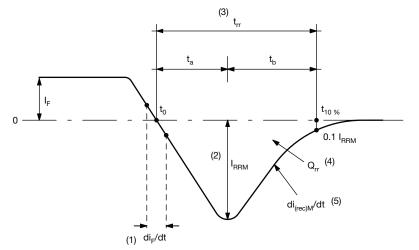


Fig. 13 - Reverse Recovery Waveform and Definitions

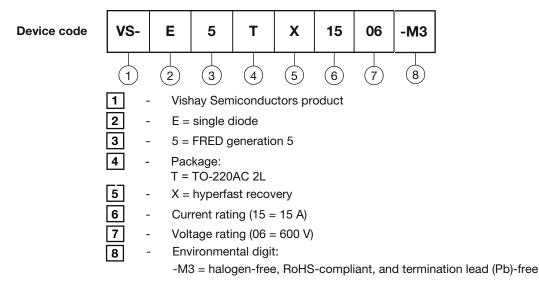
Notes

- (1) di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}$ $\,Q_{rr}^{}$ area under curve defined by $t_0^{}$ and $t_{10}^{}$ $_{\%}^{}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

⁽⁵⁾ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)							
PREFERRED P/N	PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION						
VS-E5TX1506-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS Dimensions www.vishay.com/doc?96156 Part marking information www.vishay.com/doc?95391

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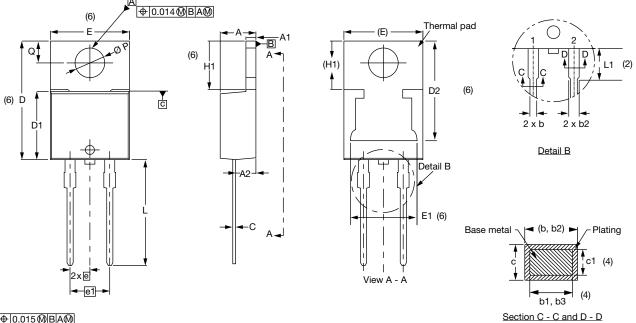
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TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIDOL	MIN.	MAX. MIN.		MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC[®] outline TO-220AC

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

(4) Dimension b1, b3, and c1 apply to base metal only

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994 $\,$

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Controlling dimensions: inches



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